# <mark>MBR1060</del>∰MBR1080, MBR1090, MBR10100</mark>

MBR1060 and MBR10100 are Preferred Devices

# SWITCHMODE<sup>™</sup> Power Rectifiers

This series of SWITCHMODE power rectifiers uses the Schottky Barrier principle with a platinum barrier metal. These state–of–the–art devices have the following features:

### Features

- Guard-Ring for Stress Protection
- Low Forward Voltage
- 175°C Operating Junction Temperature
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Low Power Loss/High Efficiency
- High Surge Capacity
- Low Stored Charge Majority Carrier Conduction
- Pb–Free Packages are Available\*

### **Mechanical Characteristics**

- Case: Epoxy, Molded
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds

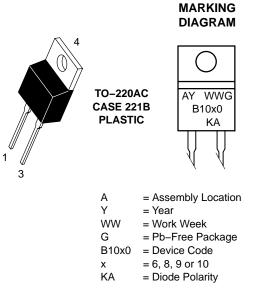


## ON Semiconductor®

http://onsemi.com

## SCHOTTKY BARRIER RECTIFIERS 10 AMPERES, 60 to 100 VOLTS





### **ORDERING INFORMATION**

Device	Package	Shipping
MBR1060	TO-220	50 Units/Rail
MBR1060G	TO-220 (Pb-Free)	50 Units/Rail
MBR1080	TO-220	50 Units/Rail
MBR1080G	TO-220 (Pb-Free)	50 Units/Rail
MBR1090	TO-220	50 Units/Rail
MBR1090G	TO-220 (Pb-Free)	50 Units/Rail
MBR10100	TO-220	50 Units/Rail
MBR10100G	TO-220 (Pb-Free)	50 Units/Rail

\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

**Preferred** devices are recommended choices for future use and best overall value.

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## MAXIMUM BATINGS HUG D

	MBR					
Rating		1060	1080	1090	10100	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		60	80	90	100	V
Average Rectified Forward Current (Rated V <sub>R</sub> ) T <sub>C</sub> = 133°C		10			А	
Peak Repetitive Forward Current (Rated V <sub>R</sub> , Square Wave, 20 kHz) T <sub>C</sub> = 133°C		20			A	
Nonrepetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)		150			A	
Peak Repetitive Reverse Surge Current (2.0 µs, 1.0 kHz)		0.5			А	
Derating Junction Temperature (Note 1) T <sub>J</sub> -65 to +175			°C			
Storage Temperature T <sub>stg</sub> -65 to +175			°C			
Voltage Rate of Change (Rated V <sub>R</sub> )	dv/dt 10,000		V/μs			

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected. 1. The heat generated must be less than the thermal conductivity from Junction–to–Ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ .

### THERMAL CHARACTERISTICS

Maximum Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	2.0	°C/W
Maximum Thermal Resistance, Junction-to-Ambient	$R_{\thetaJA}$	60	°C/W

### **ELECTRICAL CHARACTERISTICS**

	٧F	0.7 0.8 0.85 0.95	V
Maximum Instantaneous Reverse Current (Note 2) (Rated dc Voltage, $T_C = 125^{\circ}C$ ) (Rated dc Voltage, $T_C = 25^{\circ}C$ )	i <sub>R</sub>	6.0 0.10	mA

2. Pulse Test: Pulse Width = 300  $\mu$ s, Duty Cycle  $\leq$  2.0%.

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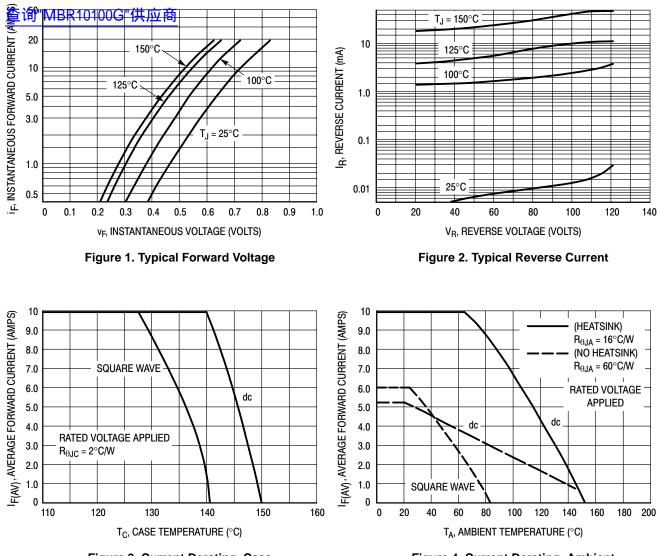


Figure 3. Current Derating, Case

Figure 4. Current Derating, Ambient

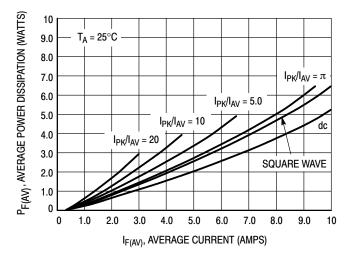
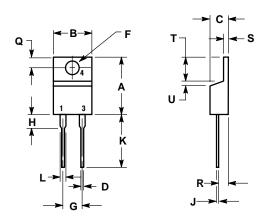


Figure 5. Forward Power Dissipation

### 查询"MBR10100G"供应商

### PACKAGE DIMENSIONS

TO-220 PLASTIC CASE 221B-04 ISSUE D



CONTROLLING DIMENSION: INCH.					
	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.595	0.620	15.11	15.75	
В	0.380	0.405	9.65	10.29	
С	0.160	0.190	4.06	4.82	
D	0.025	0.035	0.64	0.89	
F	0.142	0.147	3.61	3.73	
G	0.190	0.210	4.83	5.33	
н	0.110	0.130	2.79	3.30	
J	0.018	0.025	0.46	0.64	
K	0.500	0.562	12.70	14.27	
L	0.045	0.060	1.14	1.52	
Q	0.100	0.120	2.54	3.04	
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.14	1.39	
Т	0.235	0.255	5.97	6.48	
U	0.000	0.050	0.000	1.27	

1. DIMENSIONING AND TOLERANCING PER ANSI V14 5M 1092

NOTES

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